## Plastic NPN Silicon Medium-Power Transistors

#### **MAXIMUM RATINGS**

Rating	Symbol	MJE341	MJE344	Unit
Collector–Emitter Voltage	VCEO	150 200		Vdc
Collector–Base Voltage	VCB	175	200	Vdc
Emitter–Base Voltage	3.0	5.0	Vdc	
Collector Current — Continuous	IC	500		mAdc
Base Current	ΙΒ	250		mAdc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	20 0.16		Watts W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>Stg</sub>	-65 to +150		°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θJC	6.25	°C/W

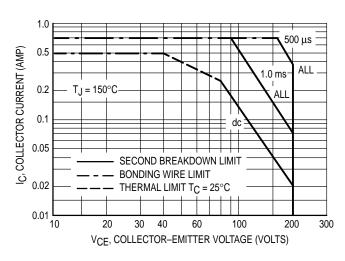


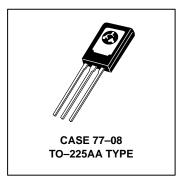
Figure 1. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I<sub>C</sub> – V<sub>CE</sub> limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation then the curves indicate.

The data of Figure 1 is based on  $T_{J(pk)}$  = 150°C;  $T_C$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} \le 150$ °C. At high case temperatures, thermal limitations will reduce the power that can be handled to values less then the limitations imposed by second breakdown.

# **MJE341 MJE344**

0.5 AMPERE
POWER TRANSISTORS
NPN SILICON
150-200 VOLTS
20 WATTS



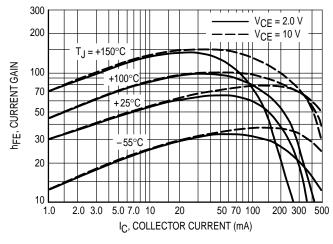




#### **MJE341 MJE344**

### **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)	MJE341 MJE344	VCEO(sus)	150 200	_ _	Vdc
Collector Cutoff Current (VCE = 150 Vdc, IB = 0) (VCE = 200 Vdc, IB = 0)	MJE341 MJE344	ICEO	_ _	1.0 1.0	mAdc
Collector Cutoff Current (VCB = 175 Vdc, IE = 0) (VCB = 200 Vdc, IE = 0)	MJE341 MJE344	ICBO	_ _	0.3 0.1	mAdc
Emitter Cutoff Current ( $V_{EB} = 3.0 \text{ Vdc}, I_{C} = 0$ ) ( $V_{EB} = 5.0 \text{ Vdc}, I_{C} = 0$ )	MJE341 MJE344	I <sub>EBO</sub>	1 1	0.1 0.1	mAdc
ON CHARACTERISTICS					
DC Current Gain ( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ ) ( $I_C = 50 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ ) ( $I_C = 150 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ )	MJE341 MJE341 MJE344 MJE341	hFE	20 25 30 20	 200 300 	_
Collector–Emitter Saturation Voltage (I <sub>C</sub> = 50 mAdc, I <sub>B</sub> = 5.0 mAdc) (I <sub>C</sub> = 150 mAdc, I <sub>B</sub> = 15 mAdc)	MJE344 MJE341	V <sub>CE(sat)</sub>	_	1.0 2.3	Vdc
Base–Emitter On Voltage (I <sub>C</sub> = 50 mAdc, V <sub>CE</sub> = 10 Vdc)		V <sub>BE(on)</sub>	_	1.0	Vdc
DYNAMIC CHARACTERISTICS					
Current–Gain — Bandwidth Product (I <sub>C</sub> = 50 mAdc, V <sub>CE</sub> = 25 Vdc, f = 10 MHz)		fΤ	15		MHz
Output Capacitance (V <sub>CB</sub> = 20 Vdc, I <sub>E</sub> = 0, f = 100 kHz)		C <sub>ob</sub>	_	15	pF
Small–Signal Current Gain (I <sub>C</sub> = 50 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)		h <sub>fe</sub>	25	_	_





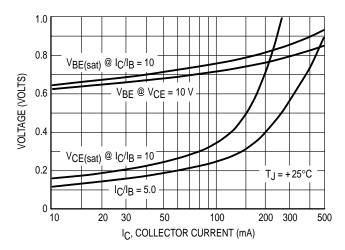
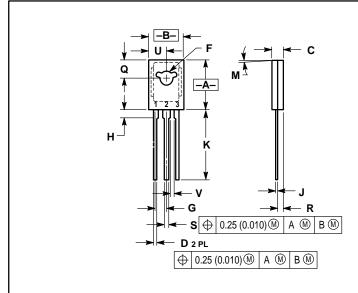


Figure 3. "On" Voltages

#### **PACKAGE DIMENSIONS**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.425	0.435	10.80	11.04	
В	0.295	0.305	7.50	7.74	
С	0.095	0.105	2.42	2.66	
D	0.020	0.026	0.51	0.66	
F	0.115	0.130	2.93	3.30	
G	0.094 BSC		2.39 BSC		
Н	0.050	0.095	1.27	2.41	
J	0.015	0.025	0.39	0.63	
K	0.575	0.655	14.61	16.63	
M	5° TYP		5° TYP		
Q	0.148	0.158	3.76	4.01	
R	0.045	0.055	1.15	1.39	
S	0.025	0.035	0.64	0.88	
U	0.145	0.155	3.69	3.93	
V	0.040		1.02		

- STYLE 1:
  PIN 1. EMITTER
  2. COLLECTOR
  3. BASE

CASE 77-08 TO-225AA TYPE **ISSUE V** 

#### **MJE341 MJE344**

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